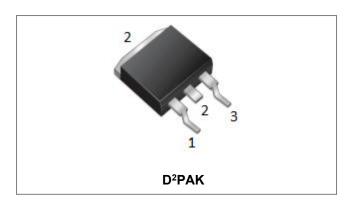


## STB40H100C

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# STB40H100C SCHOTTKY RECTIFIER



#### Features

- 175°C T<sub>J</sub> operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## Circuit Diagram



#### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current (Per Device)	lf (AV)	50% duty cycle @Tc=105°C, rectangular wave form	20(Per Leg) 40(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	300	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg) *	V <sub>F1</sub>	@ 10A, Pulse, TJ = 25 °C @ 20A, Pulse, TJ = 25 °C	0.65 0.78	0.70 0.85	V
	V <sub>F2</sub>	@ 10A, Pulse, TJ = 125 °C @ 20A, Pulse, TJ = 125 °C	0.55 0.68	0.60 0.75	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25°C	0.006	1	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 125°C	2	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 \circ C, f_{SIG} = 1MHz$	800	-	pF

\* Pulse width < 300 µs, duty cycle < 2%

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# STB40H100C

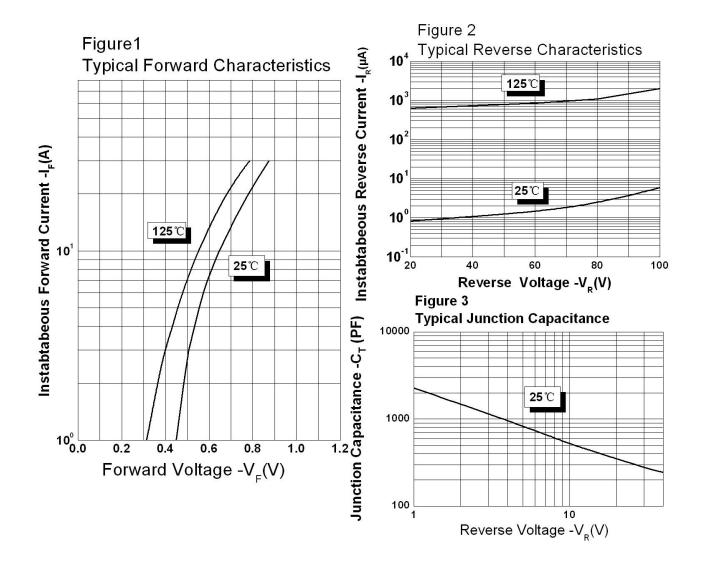
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RoHS 🗭

## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>θJC</sub>	DC operation	2	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**



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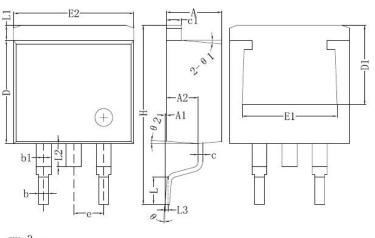


## **STB40H100C**

RoHS

## **Technical Data** Data Sheet N1835, Rev. A

## Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Dimensions in millimete		
,	Min.	Typical	Max.
Α	4.47	4.70	4.85
A1	0	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
с	0.31	0.38	0.61
c1	1.17	1.27	1.37
D	8.50	8.70	8.90
D1	6.40		
E	10.01	10.16	10.31
E1	7.6		
E2	9.98	10.08	10.31
е		2.54	
Н	14.6	15.1	15.6
L	2.00	2.30	2.74
L1	1.12	1.27	1.42
L2	1.30		2.20
L3		0.25BSC	
е	0	-	8°
e1		5°	
e2		<b>4</b> °	
e3		4°	

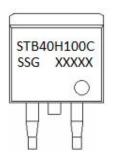
# -2- <sub>03</sub> F

## **Ordering Information**

Device	Package	Shipping
STB40H100C	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL ST

В 40

н

С

100

SSG

YΥ

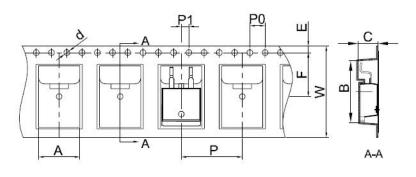
L

WW

- = Device Type
- = Package type = Forward Current (40A)
  - = Tj 175°C
  - = Reverse Voltage(100V)
  - = Configuration
  - = SSG = Year
- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## Carrier Tape Specification D<sup>2</sup>PAK



SYMBOL	Millimeters		
STINDUL	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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## STB40H100C



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